

MOS FIELD EFFECT TRANSISTOR **2SK3454**

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

The 2SK3454 is N-channel MOS FET device that features a low on-state resistance and excellent switching characteristics, and designed for high voltage applications such as DC/DC converter.

ORDERING INFORMATION

PART NUMBER	PACKAGE			
2SK3454	Isolated TO-220			

FEATURES

•Gate voltage rating $\pm 30 \text{ V}$ •Low on-state resistance RDS(on) = 0.63 Ω MAX. (VGs = 10 V, ID = 4.0 A) •Low input capacitance Ciss = 400 pF TYP. (VDs = 10 V, VGs = 0 V) •Built-in gate protection diode •Isolated TO-220 package

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (VGs = 0 V)	VDSS	250	V
Gate to Source Voltage (VDS = 0 V)	Vgss	±30	V
Drain Current(DC) (Tc = 25°C)	D(DC)	±7.0	А
Drain Current(pulse) Note1	D(pulse)	±21	А
Total Power Dissipation (T _A = 25°C)	P _{T1}	2.0	W
Total Power Dissipation (Tc = 25°C)	P _{T2}	30	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	–55 to +150	°C
Single Avalanche Current Note2	las	7.0	А
Single Avalanche Energy Note2	Eas	49	mJ

Notes1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Starting T_{ch} = 25°C, V_{DD} = 125 V, R_G = 25 Ω , V_{GS} = 20 V \rightarrow 0 V

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The mark **★** shows major revised points.

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ELECTRICAL CHARACTERISTICS (TA = 25°C)

Characteristics	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Drain Leakage Current	IDSS	V _{DS} = 250 V, V _{GS} = 0 V			100	μA
Gate Leakage Current	lgss	$V_{GS} = \pm 30 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±10	μA
Gate to Source Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	2.5		4.5	V
Forward Transfer Admittance	y _{fs}	V _{DS} = 10 V, I _D = 4.0 A	1.0			S
Drain to Source On-state Resistance	RDS(on)	Vgs = 10 V, Id = 4.0 A		0.5	0.63	Ω
Input Capacitance	Ciss	Vps = 10 V		400		pF
Output Capacitance	Coss	Vgs = 0 V		110		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		55		pF
Turn-on Delay Time	Td(on)	Vdd = 125 V, Id = 4.0 A		11		ns
Rise Time	Tr	VGS(on) = 10 V		18		ns
Turn-off Delay Time	Td(off)	R _G = 10 Ω		32		ns
Fall Time	Tf			15		ns
Total Gate Charge	QG	V _{DD} = 200 V		18		nC
Gate to Source Charge	Q _{GS}	Vgs = 10 V		3.5		nC
Gate to Drain Charge	Qgd	ID = 7.0 A		10		nC
Diode Forward Voltage	VF(S-D)	IF = 7.0 A, VGS = 0 V		1.0		V
Reverse Recovery Time	Тrr	IF = 7.0 A, VGS = 0 V		250		ns
Reverse Recovery Charge	Qrr	di/dt = 50 A/µs		1.0		μC

TEST CIRCUIT 1 AVALANCHE CAPABILITY

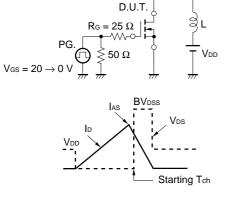
TEST CIRCUIT 2 SWITCHING TIME

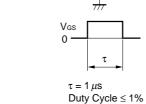
7/7

D.U.T. ¢

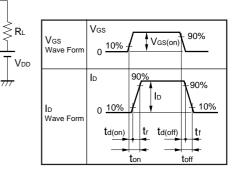
VVV.

Rg

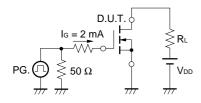




PG

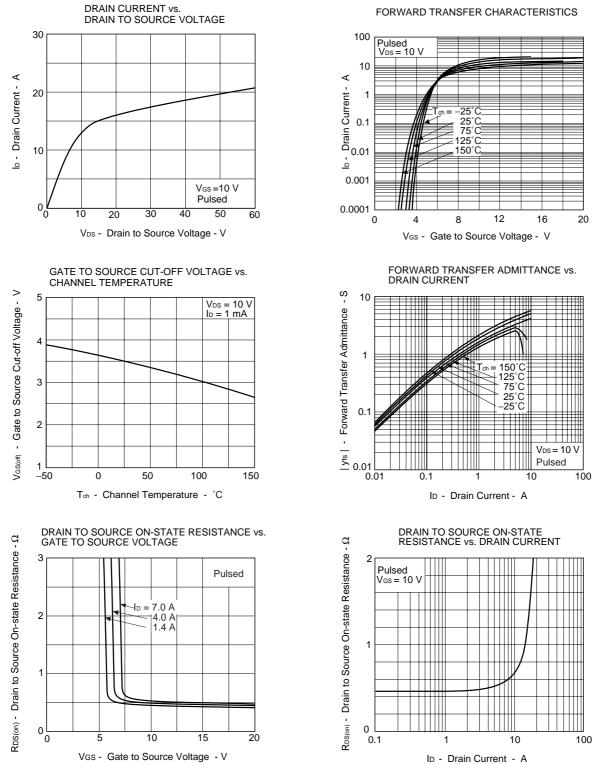


TEST CIRCUIT 3 GATE CHARGE



Data Sheet D14756EJ1V0DS00

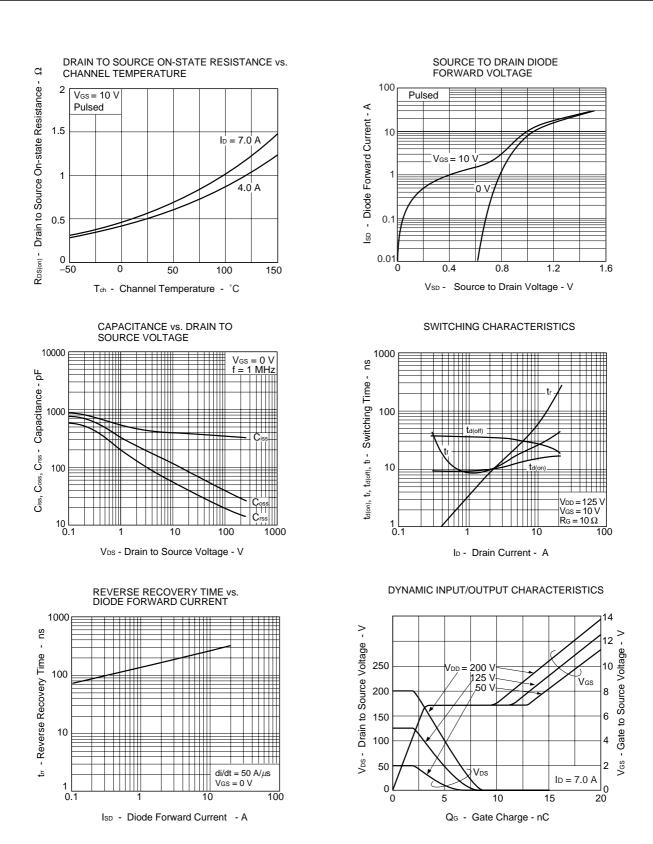
TYPICAL CHARACTERISTICS



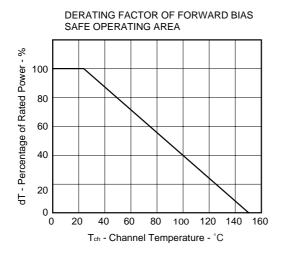
Data Sheet D14756EJ1V0DS00

FORWARD TRANSFER CHARACTERISTICS

NEC

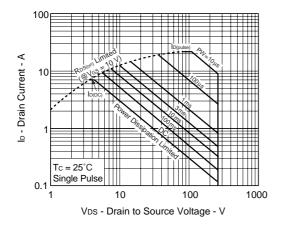


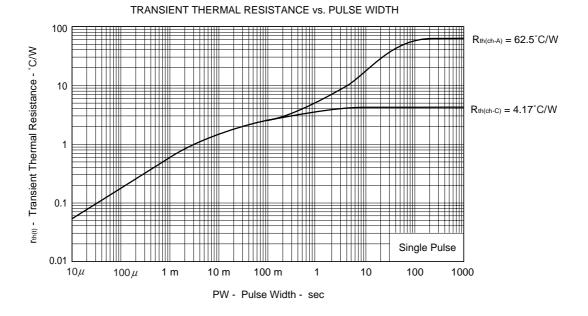
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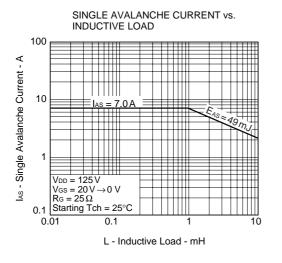
TOTAL POWER DISSIPATION vs. CASE TEMPERATURE PT - Total Power Dissipation - W 0 Tc - Case Temperature - °C

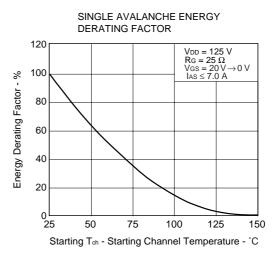
FORWARD BIAS SAFE OPERATING AREA





Data Sheet D14756EJ1V0DS00

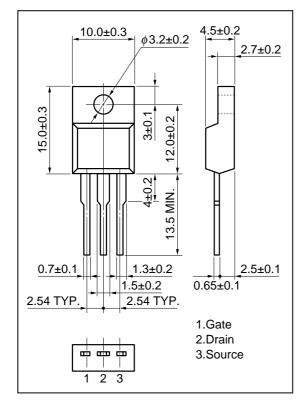




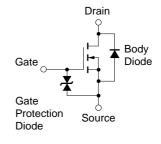
Data Sheet D14756EJ1V0DS00

PACKAGE DRAWING(Unit : mm)

Isolated TO-220 (MP-45F)



EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device. • The information in this document is current as of October, 2000. The information is subject to change without notice. For actual design-in, refer to the latest publications of NEC's data sheets or data books, etc., for the most up-to-date specifications of NEC semiconductor products. Not all products and/or types are available in every country. Please check with an NEC sales representative for availability and additional information.

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